JST08A-600B 8A TRIAC

Rev.A.1.1

DESCRIPTION:

The JST08A-600B triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. By using an internal ceramic pad, JST08A-600B provides a rated insulation voltage of 2500 VRMS, complying with UL standards (File ref: E252906). Package TO-220A is RoHS compliant.

MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	8	A
V_{DRM} /V_{RRM}	600	V
I_{GT} / / /	50/50/50/70	mA

ABSOLUTE MAXIMUM RATINGS

Parameter		Symbol	Value	Unit
Storage junction temperature range		T_{stg}	-40-150	
Operating junction temperature range		T_j	-40-125	
Repetitive peak off-state voltage (T_j=25)		V_{DRM}	600	V
Repetitive peak reverse voltage (T_j=25)		V_{RRM}	600	V
RMS on-state current (T_C 97)		$I_{T(RMS)}$	8	A
Non repetitive surge peak on-state current (full cycle , t_p=20ms , T_j=25)		I_{TSM}	80	A
Non repetitive surge peak on-state current (full cycle , t_p=16.6ms , T_j=25)			88	
I^2t value for fusing (t_p=10ms , T_j=25)		I^2t	32	A^2s
Critical rate of rise of on-state current (I_G=2 I_{GT} , f=100Hz , T_j=125)	-	dI/dt	100	A/μs
	-		50	
Peak gate current (t_p=20μs , T_j=125)		I_{GM}	4	A
Average gate power dissipation (T_j=125)		$P_{G(AV)}$	0.5	W
Peak gate power		P_{GM}	10	W

Peak pulse voltage (T_j=25 ; non-repetitive,off-state;FIG.7)	V_{pp}	1	kV

ELECTRICAL CHARACTERISTICS (T_j=25 unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	V_D=12V R_L=33Ω	- -	MAX.	50	mA
				70	
V_{GT}		ALL	MAX.	1	V
V_{GD}	V_D=V_{DRM} T_j=125 R_L=3.3kΩ	ALL	MIN.	0.2	V
I_L	I_G=1.2I_{GT}	- -	MAX.	50	mA
				100	
I_H	I_T=200mA		MAX.	60	mA
dV/dt	V_D=400V Gate Open T_j=125		MIN.	1200	V/μs
(dV/dt)c	(dI/dt)c=3.5A/ms, T_j=125		MIN.	12	V/μs
t_{on}	I_G=80mA I_A=400mA I_R=40mA T_j=25		TYP.	5	μs
t_{off}				30	

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX.)	Unit
V_{TM}	I_{TM}=11A t_p=380μs	T_j=25	1.5	V
V_{TO}	Threshold voltage	T_j=125	0.81	V
R_D	Dynamic resistance	T_j=125	44	mΩ
I_{DRM}	V_D=V_{DRM} V_R=V_{RRM}	T_j=25	5	μA
I_{RRM}		T_j=125	0.25	mA

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (AC)	2.5	/W
$R_{th(j-a)}$	junction to ambient (AC)	60	/W

ORDERING INFORMATION

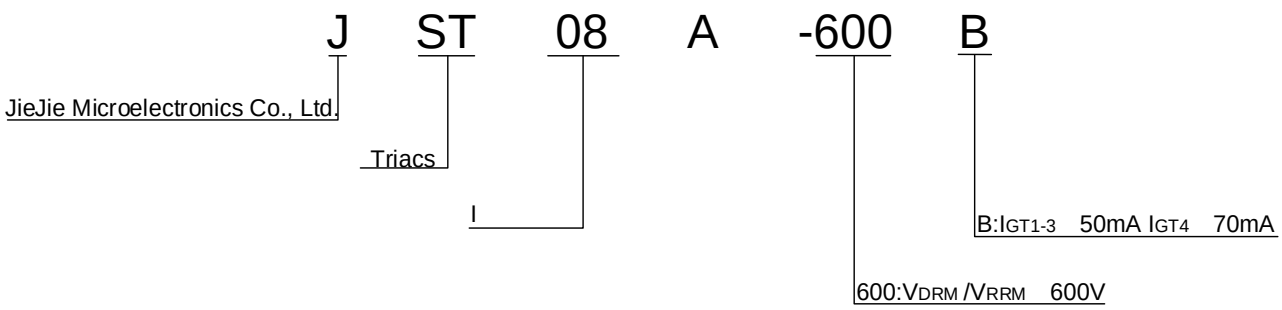


FIG.1: Maximum power dissipation versus RMS on-state current



FIG.2: RMS on-state current versus case temperature

JST08A-600B **JieJie M**

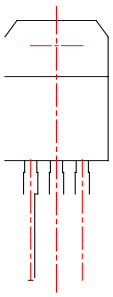
ORDERING INFORMATION

Order code	Voltage V_{DRM}/V_{RRM} (V)	IGT(mA)		Package	Base qty. (pcs)	Delivery mode
		- -				
JST08A-600B	600	50	70	TO-220A(Ins)	50	Tube

Document Revision History

Date	Revision	Changes
Apr.14, 2023	A.1.0	Last updated
Oct.13, 2025	A.1.1	Revise PACKAGE MECHANICAL DATA

PACKAGE MECHANICAL DATA



Information furnished in this document is believed to be accurate and reliable. However, Jiangsu JieJie Microelectronics Co., Ltd assumes no responsibility for the consequences of use without consideration for such information nor use beyond it. Information mentioned in this document is subject to change without notice, apart from that when an agreement is signed, Jiangsu JieJie complies with the agreement.
Products and information provided in this document have no infringement of patents. Jiangsu JieJie assumes no responsibility for any infringement of other rights of third parties which may result from the use of such products and information. This document supersedes and replaces all information previously supplied.

is a registered trademark of Jiangsu JieJie Microelectronics Co., Ltd.

Copyright © 2025 Jiangsu JieJie Microelectronics Co., Ltd. All rights reserved.